# Silicon Carbide Schottky Diode

# 1200 V, 30 A

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature dependent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operation frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 361 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

#### **Die Information**

- Wafer Diameter: 6 inch
- Die Size: 3,700 × 3,700 µm (include Scribe Lane)
- Metallization:
  - Top Ti/TiN/AlCu 4 μm
  - Back Ti/NiV/Ag
- Die Thickness: Typ. 200 μm
- Bonding Pad Size
- Anode 3,120 × 3,120 μm
- Recommended Wire Bond (Note 1)
  - Anode:  $20 \text{ mil} \times 3$

#### ELECTRICAL CHARACTERISTICS ON WAFER (T<sub>C</sub> = 25°C unless otherwise noted) (Note 2)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>R</sub>	Reverse Blocking Voltage	$I_R = 200 \ \mu A$ , $T_C = 25^{\circ}C$	1200	-	-	V
V <sub>F</sub>	Forward Voltage	$I_{F} = 30 \text{ A}, \text{ T}_{C} = 25^{\circ}\text{C}$	1.20	-	1.75	V
I <sub>R</sub>	Reverse Current	$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 25°C	-	-	200	μΑ

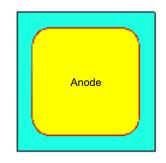
NOTES:

2. Tested 100% on wafer.



# **ON Semiconductor®**

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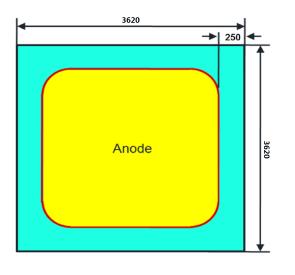
#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 3 of this data sheet.

<sup>1.</sup> Based on TO-247 package of ON Semiconductor.

#### Die Layout

#### **Cross Section**



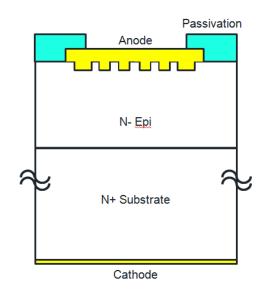
(Dimensions: µm, except Scribe Lane)

#### Figure 1. Die Layout

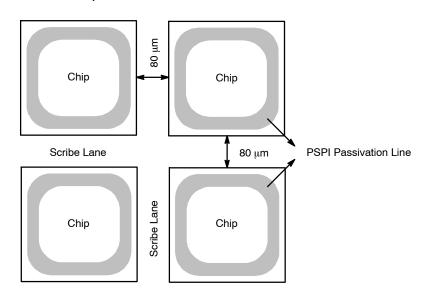
#### **Passivation Information**

- Passivation Material: Polymide (PSPI)
- Passivation Type: Local Passivation
- Passivation Thickness 90 kA

#### The Configuration of Chips (Based on 6" Wafer)









Symbol	Parameter		FFSH30120A	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		1200	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 3)		361	mJ
١ <sub>F</sub>	Continuous Rectified Forward Current @ T <sub>C</sub> < 155°C		30	А
	Continuous Rectified Forward Current @ $T_C$ <	46		
I <sub>F, Max</sub>	Non-Repetitive Peak Forward Surge Current	T <sub>C</sub> = 25°C, 10 μs	1500	А
		T <sub>C</sub> = 150°C, 10 μs	1400	А
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	230	А
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	80	А
Ptot	Power Dissipation	$T_{C} = 25^{\circ}C$	500	W
		T <sub>C</sub> = 150°C	83	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +175	°C
	TO247 Mounting Torque, M3 Screw	60	Ncm	

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 3.  $E_{AS}$  of 361 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 38$  A, V = 50 V.

#### **THERMAL CHARACTERISTICS**

Symbol	Parameter	Value	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max	0.3	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	$I_{\rm F} = 30$ A, $T_{\rm C} = 25^{\circ}{\rm C}$	-	1.45	1.75	V
		I <sub>F</sub> = 30 A, T <sub>C</sub> = 125°C	-	1.7	2.0	
		I <sub>F</sub> = 30 A, T <sub>C</sub> = 175°C	-	2.0	2.4	1
I <sub>R</sub>	Reverse Current	$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 25°C	-	-	200	μΑ
		$V_{R}$ = 1200 V, $T_{C}$ = 125°C	-	-	300	1
		$V_{R}$ = 1200 V, $T_{C}$ = 175°C	-	-	400	1
Q <sub>C</sub>	Total Capacitive Charge	V = 800 V	-	175	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	1740	-	pF
		V <sub>R</sub> = 400 V, f = 100 kHz	-	159	-	
		V <sub>R</sub> = 800 V, f = 100 kHz	-	130	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Part Number	Top Marking	Package	Packing Method	Quantity
FFSH30120A	FFSH30120A	TO-247-2L	Tube	30 units

#### **TYPICAL CHARACTERISTICS**

(T<sub>J</sub> = 25°C unless otherwise noted)

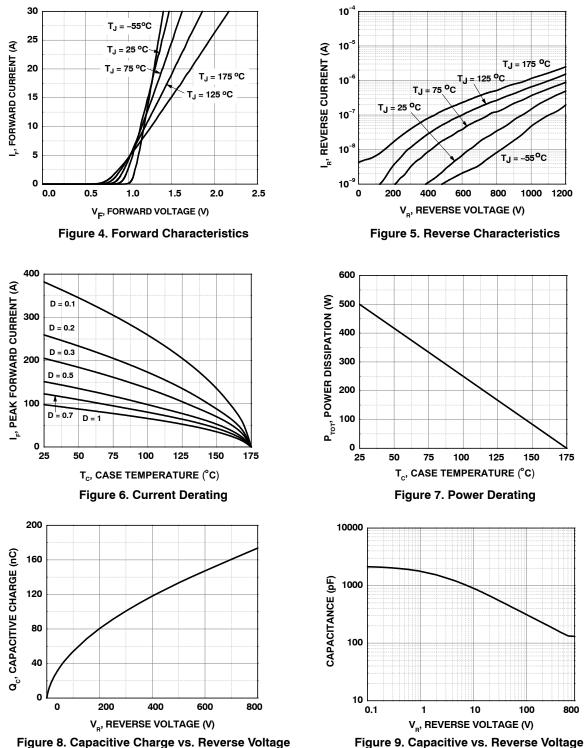
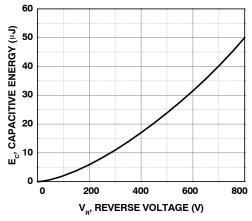


Figure 8. Capacitive Charge vs. Reverse Voltage

#### **TYPICAL CHARACTERISTICS**

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ 





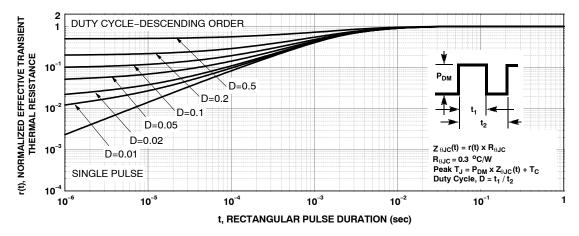


Figure 11. Junction-to-Case Transient Thermal Response Curve

#### **TEST CIRCUIT AND WAVEFORMS**

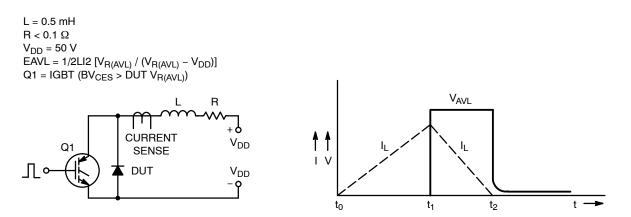


Figure 12. Unclamped Inductive Switching Test Circuit & Waveform

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